







	<h2>SI3900DV-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI3900DV-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 20V 2A 6-TSOP</p> <p>Datenblätter:  SI3900DV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 43685 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3900DV-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 20V 2A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	43685 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	830mW
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2A
Rds On (Max) @ Id, Vgs	125 mOhm @ 2.4A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	4nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)















































SI3900DV-T1-GE3 ist neu im Original, Suche SI3900DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3900DV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3900DV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3905DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 8V 6-TSOP</p>	 <p>SI3905DV-T1-E3 Vishay / Siliconix MOSFET 2P-CH 8V 6-TSOP</p>	 <p>SI3900DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 2A 6-TSOP</p>	 <p>SI3905DV-T1 SILICON SI3905DV-T1 SILICON</p>
 <p>SI3900DV-T1-E3 Vishay / Spectrol MOSFET 2N-CH 20V 2A 6-TSOP</p>	 <p>SI3900DV VISHAY SI3900DV VISHAY</p>	 <p>SI3879DV-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 5A 6-TSOP</p>	 <p>SI3905DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 8V 6-TSOP</p>

heiße Teile

Mehr

 SI3853DV-T1-E3	 SI3861BDV-T1-GE3	 SI3861BDV-T1-GE3	 SI3861DV-NL	 SI3861DV-T1-E3
 SI3863BDV-T1-GE3	 SI3863DV-T1-E3	 SI3863DV-T1-GE3	 SI3865BDV-T1-E3	 SI3865BDV-T1-E3
 SI3865CDV-T1-GE3	 SI3865CDV-T1-GE3	 SI3865DV-T1	 SI3865DV-T1-E3	 SI3865DV-T1-GE3
 SI3867DV-T1-E3	 SI3867DV-T1-E3	 SI3867DV-T1-GE3	 SI3867DV-T1-GE3	 SI3879DV-T1-E3
 SI3879DV-T1-E3	 SI3900DV	 SI3900DV-T1-E3	 SI3900DV-T1-E3	 SI3900DV-T1-GE3
 SI3905DV-T1	 SI3905DV-T1-E3	 SI3905DV-T1-E3	 SI3905DV-T1-GE3	 SI3905DV-T1-GE3
 SI3909DV-T1	 SI3909DV-T1-E3	 SI3909DV-T1-E3	 SI3909DV-T1-GE3	 SI3909DV-T1-GE3
 SI3911DV	 SI3911DV-T1	 SI3911DV-T1-E3	 SI3911DV-T1-E3	 SI3911DV-T1-G33
 SI3911DV-T1-GE3	 SI3911DV-T3-E3	 SI3915DV	 SI3915DV-T1-E3	 SI3915DV-T1-GE3
 SI3932DV-T1-GE3	 SI3932DV-T1-GE3	 SI3948DV-T1	 SI3948DV-T1-E3	 SI3948DV-T1-E3

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